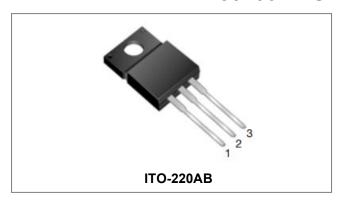




### MBRF30200CT SCHOTTKY RECTIFIER



#### **Features**

- 150°C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Circuit Diagram**



#### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

### **Maximum Ratings:**

| Characteristics                   | Symbol              | Condition                             | Max.           | Units |  |
|-----------------------------------|---------------------|---------------------------------------|----------------|-------|--|
| Peak Repetitive Reverse Voltage   | $V_{RRM}$           | -                                     |                |       |  |
| Working Peak Reverse Voltage      | $V_{RWM}$           |                                       | 200            | V     |  |
| DC Blocking Voltage               | $V_R$               |                                       |                |       |  |
| Average Rectified Forward Current | I <sub>F (AV)</sub> | 50% duty cycle @Tc=133°C, rectangular | 15(Per Leg)    | A     |  |
|                                   |                     | wave form                             | 30(Per Device) |       |  |
| Peak Repetitive Forward           | lea                 | Rated V <sub>R</sub> square wave,     | 20             | Α     |  |
| Current(Per Leg)                  | IFRM                | 20KHz T <sub>C</sub> = 133°C          | 20             |       |  |
| Peak One Cycle Non-Repetitive     | lea                 | 8.3ms, Half Sine pulse                | 150            | Α     |  |
| Surge Current(Per Leg)            | IFSM                | 6.3ms, mair Sine puise                | 150            |       |  |

### **Electrical Characteristics:**

| Characteristics  | Symbol           | Condition   | Тур.  | Max.   | Units |
|--|------------------|---|-------|--------|-------|
| Forward Voltage Drop(Per Leg)* V <sub>F1</sub>                                     |                  | @ 15A, Pulse, T <sub>J</sub> = 25 °C  | 0.79  | 0.90   | V     |
|  | V <sub>F2</sub>  | @ 15A, Pulse, T <sub>J</sub> = 125 °C   | 0.68  | 0.75   | V     |
| Reverse Current(Per Leg)*  |                  | $@V_R = \text{rated } V_{R,} T_J = 25 ^{\circ}\text{C}$   | 0.001 | 1.0    | mA    |
|  | I <sub>R2</sub>  | $@V_R = \text{rated } V_{R}, T_J = 125  ^{\circ}\text{C}$   | 0.006 | 6.0    | mA    |
| Junction Capacitance(Per Leg)  | C <sub>⊤</sub>   | $C_T$ @V <sub>R</sub> = 5V, $T_C$ = 25 °C, $f_{SIG}$ = 1MHz   |       | 400    | pF    |
| Series Inductance(Per Leg)   | Ls               | Measured lead to lead 5 mm from package body  | 8.0   | -      | nH    |
| Voltage Rate of Change   | dv/dt            | -   |       | 10,000 | V/μs  |
| RSM Isolation Voltage<br>(t = 1.0 second, R. H. < =30%,<br>T <sub>A</sub> = 25 °C) | V <sub>ISO</sub> | Clip mounting, the epoxy body away from the heatsink edge by more than 0.110" along the lead direction. | -     | 4500   | V     |
| ,  |                  | Clip mounting, the epoxy body is inside the heatsink.   | -     | 3500   |       |
|  |                  | Screw mounting, the epoxy body is inside the heatsink.  | -     | 1500   |       |

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •

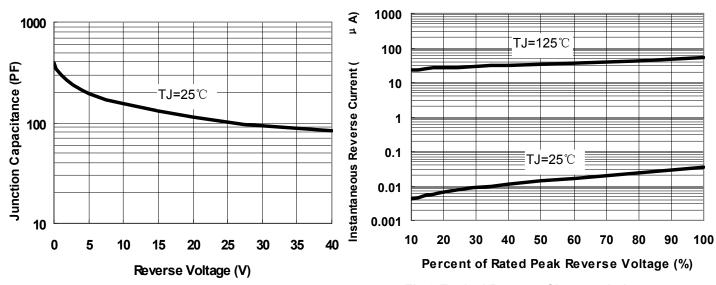




## **Thermal-Mechanical Specifications:**

| Characteristics                                      | Symbol            | Condition    | Specification | Units |
|--|-------------------|--------------|---------------|-------|
| Junction Temperature                                 | TJ                | -            | -55 to +150   | °C    |
| Storage Temperature                                  | T <sub>stg</sub>  | -            | -55 to +150   | °C    |
| Typical Thermal Resistance Junction to Case(Per Leg) | R <sub>0</sub> JC | DC operation | 3.5           | °C/W  |
| Approximate Weight                                   | wt                | -            | 2             | g     |
| Case Style   | ITO-220AB         |              |               |       |

# **Ratings and Characteristics Curves**



**Fig.1-Typical Junction Capacitance** 

Fig.2-Typical Reverse Characteristics

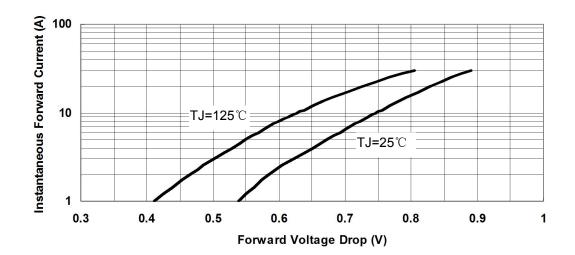


Fig.3-Typical Instantaneous Forward Voltage Characteristics

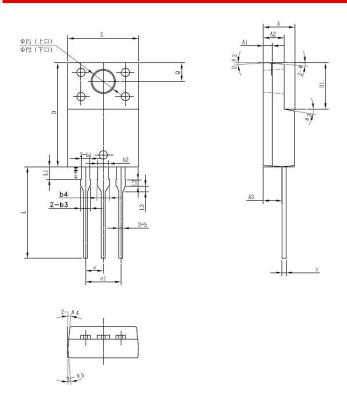
- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •





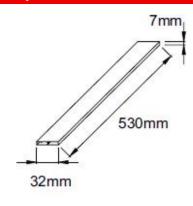


### **Mechanical Dimensions ITO-220AB**

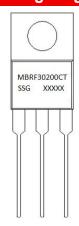


| SYMBOL          | Millimeters |       |       |  |
|-----------------|-------------|-------|-------|--|
| STWIBUL         | MIN.        | TYP.  | MAX.  |  |
| Α               | 4.30        | 4.50  | 4.70  |  |
| A1              | 1.10        | 1.30  | 1.50  |  |
| A2              | 2.80        | 3.00  | 3.20  |  |
| A3              | 2.50        | 2.70  | 2.90  |  |
| b               | 0.50        | 0.60  | 0.75  |  |
| b1              | 1.10        | 1.20  | 1.35  |  |
| b2              | 1.50        | 1.60  | 1.75  |  |
| b3              | 1.20        | 1.30  | 1.45  |  |
| b4              | 1.60        | 1.70  | 1.85  |  |
| С               | 0.50        | 0.60  | 0.75  |  |
| D               | 14.80       | 15.00 | 15.20 |  |
| E               | 9.96        | 10.16 | 10.36 |  |
| е               |             | 2.55  |       |  |
| e1              |             | 5.10  |       |  |
| H1              | 6.50        | 6.70  | 6.90  |  |
| L               | 12.70       | 13.20 | 13.70 |  |
| L1              | 1.60        | 1.80  | 2.00  |  |
| L2              | 0.80        | 1.00  | 1.20  |  |
| L3              | 0.60        | 0.80  | 1.00  |  |
| ФР1( 上□)        | 3.30        | 3.50  | 3.70  |  |
| <b>ΦP2</b> (下口) | 2.99        | 3.19  | 3.39  |  |
| Q               | 2.50        | 2.70  | 2.90  |  |
| Θ1              |             | 5°    |       |  |
| Θ2              |             | 4°    |       |  |
| Θ3              |             | 10°   |       |  |
| Θ4              |             | 5°    |       |  |
| Θ5              |             | 5°    |       |  |

# **Tube Specification**



### **Marking Diagram**



#### Where XXXXX is YYWWL

 MBR
 = Device Type

 F
 = Package type

 30
 = Forward Current (30A)

 200
 = Reverse Voltage (200V)

 CT
 = Configuration

 SSG
 = SSG

 YY
 = Year

WW = Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

### **Ordering Information**

| Device      | Package                | Shipping     |
|-------------|------------------------|--------------|
| MBRF30200CT | ITO-220AB<br>(Pb-Free) | 50 pcs/ tube |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

- China Germany Korea Singapore United States •
- http://www.smc-diodes.com sales@ smc-diodes.com •





#### DISCLAIMER:

- 1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC Sangdest Microelectronics (Nanjing) Co., Ltd sales department for the latest version of the datasheet(s).
- 2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.
- 3- In no event shall SMC Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC Sangdest Microelectronics (Nanjing) Co., Ltd assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.
- 4- In no event shall SMC Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.
- 5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC Sangdest Microelectronics (Nanjing) Co.. Ltd.
- 6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC Sangdest Microelectronics (Nanjing) Co., Ltd.
- 7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations.

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by SMC Diode manufacturer:

Other Similar products are found below:

MA4E2039 MA4E2508M-1112 MBR10100CT-BP MBR1545CT MMBD301M3T5G GS1JE-TP RB160M-50TR BAS 3010S-02LRH E6327
BAT 54-02LRH E6327 NSR05F40QNXT5G NSVR05F40NXT5G NTE555 JANS1N6640 SB07-03C-TB-H SB1003M3-TL-W
SBAT54CWT1G SBM30-03-TR-E SK310-T SK33A-TP SK34B-TP SS3003CH-TL-E PDS3100Q-7 GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBRB30H30CT-1G BAS 70-02L E6327 DMJ3940-000 SB007-03C-TB-E SB10015M-TL-E SB1003M3-TL-E SK32A-TP SK33B-TP SK35A-TP SK38B-TP NTE505 NTSB30U100CT-1G VS-6CWQ10FNHM3 CRG04(T5L,TEMQ)
ACDBA1100LR-HF ACDBA1200-HF ACDBA140-HF ACDBA2100-HF ACDBA240-HF ACDBA3100-HF CDBQC0530L-HF BAT54-13-F ACDBA340-HF ACDBA260LR-HF